



#### **QUADRUPLE 3-STATE BUFFERS OF HIGH**

### **Description**

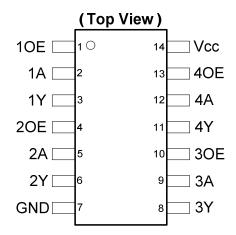
The 74AHCT126 provides four independent buffer gates with 3-state outputs. Each buffer has a separate enable pin that if driven with a low logic level, places the corresponding output in the high impedance state. The device is designed for operation with a power supply range of 4.5V to 5.5V.

#### **Features**

Notes:

- Wide Supply Voltage Range from 4.5V to 5.5V
- Inputs Are TTL Voltage Level Compatible
- Outputs Sink or Source 8mA at V<sub>CC</sub> = 4.5V
- CMOS Low Power Consumption
- Schmitt Trigger Action at All Inputs
- ESD Protection Exceeds JESD 22
  - 200-V Machine Model (A115)
  - 2000-V Human Body Model (A114)
  - Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

### **Pin Assignments**



SO-14 / TSSOP-14

### **Applications**

- General Purpose Logic
- Wide Array of Products Such as:
  - PCs, Networking, Notebooks, Netbooks
  - Computer Peripherals, Hard Drives, CD/DVD ROMs
  - TVs, DVDs, DVRs, Set Top Boxes

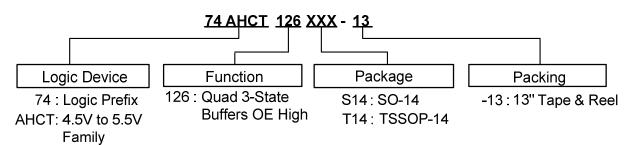
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



## **Ordering Information**



Part Number	Bookaga Cada	Dockoning	7" Tape	and Reel
Part Number	Package Code	Packaging	Quantity	Part Number Suffix
74AHCT126S14-13	S14	SO-14	2,500/Tape & Reel	-13
74AHCT126T14-13	T14	TSSOP-14	2,500/Tape & Reel	-13

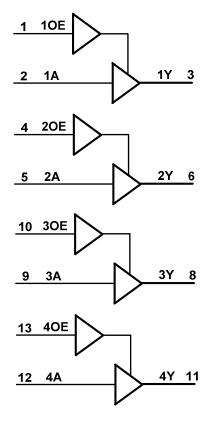
## **Pin Descriptions**

Pin Number	Pin Name	Function
1	10E	Data Enable Input (active high)
2	1A	Data Input
3	1Y	Data Output
4	20E	Data Enable Input (active high)
5	2A	Data Input
6	2Y	Data Output
7	GND	Ground
8	3Y	Data Output
9	3A	Data Input
10	30E	Data Enable Input (active high)
11	4Y	Data Output
12	4A	Data Input
13	40E	Data Enable Input (active high)
14	Vcc	Supply Voltage

## **Function Table**

Inp	Output	
OE	Α	Υ
Н	Н	Н
Н	L	L
L	X	Z

## **Logic Diagram**





# **Absolute Maximum Ratings** (Note 4) (T<sub>A</sub> = +25 ℃, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
V <sub>CC</sub>	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range	-0.5 to +7.0	V
I <sub>IK</sub>	Input Clamp Current V <sub>I</sub> < -0.5V	-20	mA
lok	Output Clamp Current Vo < 0 V	-20	mA
lok	Output Clamp Current Vo > Vcc	20	mA
lo	Continuous Output Current 0V < V <sub>O</sub> < V <sub>CC</sub>	+/- 25	mA
I <sub>CC</sub>	Continuous Current Through V <sub>CC</sub>	50	mA
I <sub>GND</sub>	Continuous Current Through GND	-50	mA
TJ	Operating Junction Temperature	-40 to +150	.€
T <sub>STG</sub>	Storage Temperature	-65 to +150	℃
Ртот	Total Power Dissipation	500	mW

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

## Recommended Operating Conditions (Note 5) (T<sub>A</sub> = +25 °C, unless otherwise specified.)

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage	4.5	5.5	V
VI	Input Voltage	0	5.5	V
Vo	Output Voltage	0	V <sub>CC</sub>	V
Δt/ΔV	Input transition Rise or Fall Rate	-	20	ns/V
TA	Operating Free-Air Temperature	-40	+125	℃

Note: 5. Unused inputs should be held at  $V_{CC}$  or Ground.



## **Electrical Characteristics**

Cumbal	Dawamatan	Took Conditions	Vcc	T <sub>A</sub> = -40 °C	T <sub>A</sub> = -40 °C to +85 °C		T <sub>A</sub> = -40 °C to +125 °C	
Symbol	Parameter	Test Conditions	VCC	Min	Max	Min	Max	Unit
V <sub>IH</sub>	High-Level Input Voltage	-	4.5V to 5.5V	2.0	-	2.0	-	٧
V <sub>IL</sub>	Low-Level Input Voltage	-	4.5V to 5.5V	-	0.8	-	0.8	<b>V</b>
V	High-Level Output	I <sub>OH</sub> = -50μA	4.5V	4.4	-	4.4	-	V
V <sub>OH</sub>	Voltage	I <sub>OH</sub> = -8mA	4.5V	3.80	-	3.70	-	V
.,	Low-Level Output	I <sub>OL</sub> = 50μA	4.5V	-	0.1	-	0.1	V
V <sub>OL</sub>	Voltage	I <sub>OL</sub> = 8mA	4.5V	-	0.44	-	0.55	V
l <sub>OZ</sub>	Z State Leakage Current	V <sub>O</sub> = 0 to 5.5V	5.5V	-	±2.5	-	±10	μA
l <sub>l</sub>	Input Current	$V_I = GND$ to 5.5V	3.6V	-	±1	-	±2	μΑ
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}, I_O = 0$	3.6V	-	20	-	40	μΑ
Δlcc	Additional Supply Current	One input at V <sub>CC</sub> –2.1V Other pins at V <sub>CC</sub> or GND	5.5V	-	1.35	-	5	mA

# **Operating Characteristics**

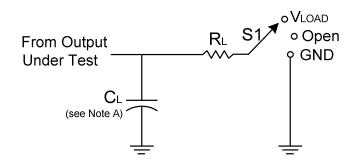
Parameter		Test	V <sub>CC</sub> = 5.5V	Unit
		Conditions	Тур	Oilit
C <sub>pd</sub>	Power Dissipation Capacitance per Gate	f = 1MHz	14.8	pF
C <sub>i</sub>	Input Capacitance	$V_i = V_{CC} - or$ GND	4.0	pF

# **Switching Characteristics** (V<sub>CC</sub> = 4.5V to 5.5V)

Symbol	Parameter	Test Conditions	T	A = +25°	С	-40℃ to	o +85°C	-40 ℃ to	+125℃	Unit
Syllibol	Parameter	rest Conditions	Min	Тур	Max	Min	Max	Min	Max	Ollit
	Dramanation Dalay A. to V	Figure 1 C <sub>L</sub> = 15pF	0.5	3.0	5.5	0.5	6.5	0.5	7.0	
t <sub>PD</sub>	Propagation Delay A <sub>N</sub> to Y <sub>N</sub>	Figure 1 C <sub>L</sub> = 50pF	0.5	4.3	7.5	0.5	8.5	0.5	9.5	ns
	Enable Time OE <sub>N</sub> to Y <sub>N</sub>	Figure 1 C <sub>L</sub> = 15 pF	0.5	3.3	5.1	0.5	6.0	0.5	6.5	20
t <sub>EN</sub>	LINADIR TIME OLN TO TN	Figure 1 C <sub>L</sub> = 50pF	0.5	4.7	7.1	0.5	8.0	0.5	9.0	ns
	Disable Time OE <sub>N</sub> to Y <sub>N</sub>	Figure 1 C <sub>L</sub> = 15pF	0.5	4.8	6.8	0.5	8.0	0.5	8.5	20
t <sub>DIS</sub>	DISABLE TIME OLN TO TH	Figure 1 C <sub>L</sub> = 50pF	0.5	6.5	8.9	0.5	10.0	0.5	11.5	ns

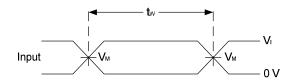


### **Parameter Measurement Information**

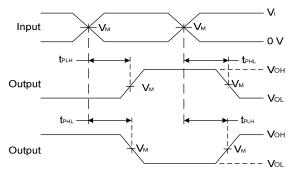


TEST	S1
tplh/tphl	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	Vload
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

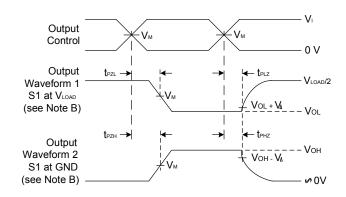
Voc	Inputs		V <sub>M</sub> V <sub>M</sub>		V	0	Б	V.
Vcc	VI	t <sub>r</sub> /t <sub>f</sub>		Outputs	VLOAD	CL	KL	$\mathbf{V}\Delta$
4.5V to 5.5V	3 V	≤3ns	1.5 V	V <sub>CC</sub> /2	V <sub>CC</sub>	15pF, 50pF	1K	0.3V



#### **Voltage Waveform Pulse Duration**



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs



Voltage Waveform Enable and Disable Times Low and High Level Enabling

Figure 1. Load Circuit and Voltage Waveforms

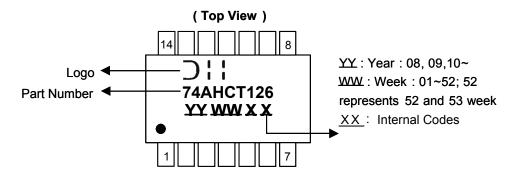
Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 1 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis.</sub>
- E. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>EN0</sub>
- F.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{PD.}$



## **Marking Information**

#### (1) SO-14, TSSOP-14



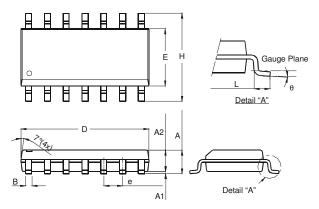
Part Number	Package
74AHCT126S14	SO-14
74AHCT126T14	TSSOP-14



### Package Outline Dimensions (All dimensions in mm.)

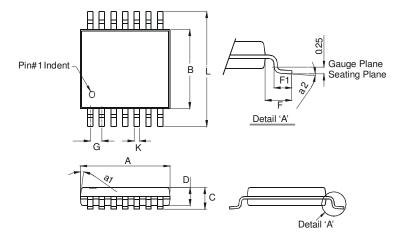
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

#### Package Type: SO-14



	SO-14	
Dim	Min	Max
Α	1.47	1.73
A1	0.10	0.25
A2	1.45	Тур
В	0.33	0.51
D	8.53	8.74
Е	3.80	3.99
е	1.27	Тур
Н	5.80	6.20
L	0.38	1.27
θ	0°	8°
All Din	nensions	in mm

### Package Type: TSSOP-14



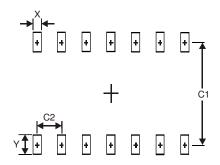
TSSOP-14			
Dim	Min	Max	
a1	7° (4X)		
a2	0°	8°	
Α	4.9	5.10	
В	4.30	4.50	
၁		1.2	
D	0.8	1.05	
F	1.00 Typ		
F1	0.45	0.75	
G	0.65 Typ		
K	0.19	0.30	
L	6.40 Typ		
All Dimensions in mm			



### **Suggested Pad Layout**

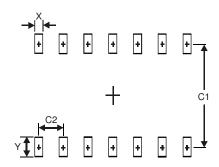
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

#### Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Υ	1.50
C1	5.4
C2	1.27

#### Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Υ	1.45
C1	5.9
C2	0.65



#### **IMPORTANT NOTICE**

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel

Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application. Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

#### LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2015, Diodes Incorporated

www.diodes.com

9 of 9 74AHCT126 April 2015 © Diodes Incorporated Document number: DS35356 Rev. 3 - 2

# 单击下面可查看定价,库存,交付和生命周期等信息

>>Diodes Incorporated(达迩科技(美台))